		Reg. No. :										
Question Paper Code: R1P03												
B.E. / B.Tech. DEGREE EXAMINATION, NOV 2024												
	First Semester											
	Computer science Engineering											
R21UPH103- ENGINEERING PHYSICS												
	(Common to ALL CSE allied branches)											
(Regulations 2021)												
Dur	ation: Three hours]	Maxi	imun	n: 10	00 M	arks	
	Answer All Questions											
	PART A - (10 x 1 = 10 Marks)											
1.	In the HCP crystal stru	ucture, the edge at	om can	share	only		poi	rtion	•		CO	1 -U
	(a) 1/6	(b) 1/4	(0	c) 1/8				(d) 1	/2			
2.	A particular metal has each unit cell?	a BCC unit cell. I	How ma	any ato	oms of	the n	netal	are i	n		CO	1-U
	(a) 1	(b) 4	(0	c) 6				(d) 2	2			
3.	Which of the followin	g is the not the pro	operty o	of laser	?						CO	1-U
	(a)Multicolor (b)Unidirectional											
	(c)Coherent			(d)Inter	nse							
4.	Air wedge is work une	der the principle c	alled								CO	1 - U
	(a)Scattering	(b) Refraction	(c)	Disper	sion		(d)	Inter	rfere	ence		
5.	In a finite Potential we	ell, the wave funct	tion of a	a partic	le outs	ide tl	he bo	ox is			CO	1-U
	(a)zero	(b)infinite		(c)cons	tant			(d)	varia	ble		
6.	De-Broglie wavelengt	h of electron acce	lerated	throug	h a pot	entia	l of 1	150V	' is	C	CO4-	App
	(a)1.0Å	(b) 1.33 Å		(c) 3.14	1Å			(d)2	.0Å			
7.	The zero resistive mat	erials are also gen	erally c	alled a	S	mate	erials	5			CO	1 - U
	(a) Superconducting	(b) Non-conduc	cting	(c) Ser	nicond	uctir	ıg	(d) (Cond	luctir	ıg	

8.	The Compound semiconductor emits during the transfer of electron from conduction band to valence band.							
	(a) H	Photon	(b) Phonon	(c) Proton	(d) Electron			
9.	Semiconducting material has electrical conductivity greater than CC							
	(a) i	nsulator	(b) metals	(c) alloys	(d) conductor			
10.	Free	electrons moving	ingin the crystalcan be compared to the motion of CO1-U					
	(a) c	lust particles	(b) stars in sky PART – B (5 x	(c) water bubbles 2= 10Marks)	(d) gas molec	cules		
11.	Wha	nt are Bravais Latt	ices?			CO1-U		
12.	What are the characteristics of laser?							
13.	Calculate the de-Broglie wavelength of an electron which has been accelerated CO4- App from rest on application of potential of 400volts.							
14.	. Define mean free path. CC							
15.	Distinguish between intrinsic & extrinsic semiconductor.					CO1-U		
16.	(a)	(i) Show that successive plane	PART – C (5 for a cubic lattice t (h k l) is given by	x 16= 80Marks) he distance between t	wo CO1-U	(12)		
	$d = \frac{a}{\sqrt{h^2 + k^2 + l^2}}$							
	(ii) Show that the atomic radius of SC and HCP are the same.							
	(b)	(i) Show that the	Or atomic packing facto	or of FCC and HCP are	the CO1-U	(12)		
		(ii) Show that the same.	e Coordination numbe	er of FCC and HCP are	the	(4)		
17.	(a)	Describe a methowedge?	od to find the thickne	ss of the wire using an	air CO2-U	(16)		
	Or							
	(b)	Explain the cons necessary diagram	truction and energy le ms.	vel of a CO ₂ laser with	the CO2-U	(16)		

18.	(a)	Compute the Compton shift of a photon for the scattering angle (θ =180°)	CO4-App	(16)		
Or						
	(b)	Compute the Schrödinger time-dependent and time-independent wave equation.	CO4-App	(16)		
19.	(a)	Derive the expression for electrical conductivity of metals. Show that the ratio betweenthermal conductivity and electrical conductivity is directly proportional to absolute temperature (T). Or	CO1-U	(16)		
	(b)	Derive an expression for Fermi energy (E_F) from density of energy states in a conducting material.	CO1-U	(16)		
20.	(a)	Assuming the Fermi - Dirac distribution function, derive an expression for the concentration of electrons per unit volume and concentration of holes per unit volume in an intrinsic semiconductor.	CO1-U	(16)		
		Or				
	(b)	Explain Hall effect in semiconductors. Derive an expression for Hall coefficient of a p-type and p-type semiconductors. Describe	CO1-U	(16)		

Hall coefficient of a p-type and n-type semiconductors. Describe the experimental setup for the measurement of Hall coefficient.

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